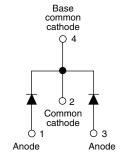


Vishay Semiconductors

Schottky Rectifier, 2 x 3 A



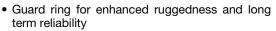


DAK	(TO-252AA)
D-PAK (1U-252AA

PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	2 x 3 A					
V _R	50 V, 60 V					
V _F at I _F	0.65 V					
I _{RM}	15 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	6 mJ					

FEATURES

• Low forward voltage drop





 Halogen-free according to IEC 61249-2-21 HALOGEN definition

FREE

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-MBRD650CT-M3, VS-MBRD660CT-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	6	A						
V _{RRM}		50/60	V						
I _{FSM}	t _p = 5 μs sine	490	А						
V _F	3 Apk, T _J = 125 °C (per leg)	0.65	V						
T _J	Range	- 40 to 150	°C						

VOLTAGE RATINGS								
PARAMETER	VS-MBRD660CT-M3	UNITS						
Maximum DC reverse voltage	V_{R}	50	60	V				
Maximum working peak reverse voltage	V_{RWM}	50	00	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average per leg		l	50 % distributed at T 100 % vector and an unsurface		3.0			
See fig. 5	1 (AV)		6	Α				
Maximum peak one cycle non-repetitive surge current See fig. 7		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	A		
			10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75			
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6	mJ		
Repetitive avalanche curre	nt per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		0.6	Α		

VS-MBRD650CT-M3, VS-MBRD660CT-M3

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Schottky Rectifier, 2 x 3 A



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Revision: 03-Nov-10

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		3 A	T _{.1} = 25 °C	0.7			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	6 A	11 = 23 0	0.9	V		
See fig. 1	VFM (**)	3 A	T _{.1} = 125 °C	0.65	v		
		6 A	1J = 125 C	0.85			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.1	mΛ		
See fig. 2		T _J = 125 °C	v _R = nateu v _R	15	- mA		
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		145	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.0	nΗ		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C			
Maximum thermal resistance,	per leg	R_{thJC}	DC operation	6				
junction to case	per device		See fig. 4	3	°C/W			
Maximum thermal resistance, junction to ambient		R_{thJA}		80				
A intil-t				0.3	g			
Approximate weight				0.01	oz.			
Madina desira			Case style D-PAK (similar to TO-252AA)	MBRD650CT				
Marking device			Case style D-FAR (sittilial to TO-232AA)	MBRD660CT				

Note



Schottky Rectifier, 2 x 3 A

Vishay Semiconductors

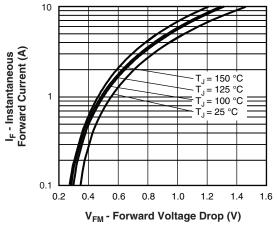


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

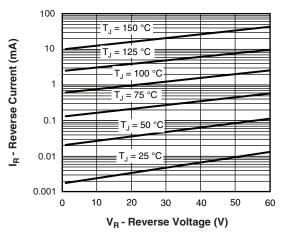


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

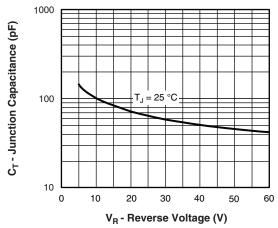


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

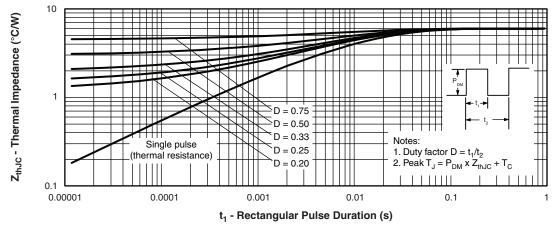


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

VS-MBRD650CT-M3, VS-MBRD660CT-M3

Vishay Semiconductors

Schottky Rectifier, 2 x 3 A



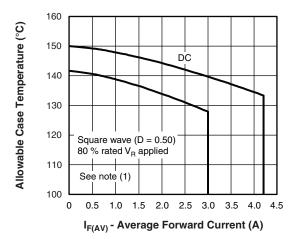


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

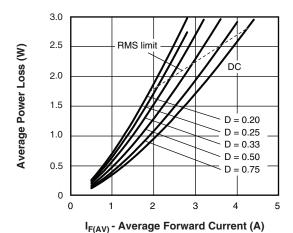


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

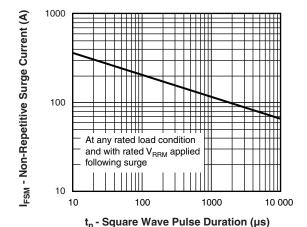


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{th,JC}}; \\ \text{Pd} = \text{Forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = 80 \text{ \% rated V}_{\text{R}} \\ \end{array}$

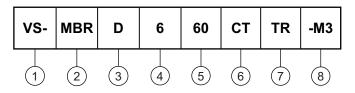
VS-MBRD650CT-M3, VS-MBRD660CT-M3

Schottky Rectifier, 2 x 3 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky MBR series

3 - D = TO-252AA (D-PAK)

4 - Current rating (6 = 6 A)

- Voltage ratings 50 = 50 V 60 = 60 V

6 - CT = Center tap (dual)

None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBRD650CT-M3	75	3000	Antistatic plastic tube						
VS-MBRD650CTTR-M3	2000	2000	13" diameter reel						
VS-MBRD650CTTRL-M3	3000	3000	13" diameter reel						
VS-MBRD650CTTRR-M3	3000	3000	13" diameter reel						
VS-MBRD660CT-M3	75	3000	Antistatic plastic tube						
VS-MBRD660CTTR-M3	2000	2000	13" diameter reel						
VS-MBRD660CTTRL-M3	3000	3000	13" diameter reel						
VS-MBRD660CTTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95016</u>					
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



Vishay Semiconductors

NOTES

3

2

MAX.

0.410

0.070

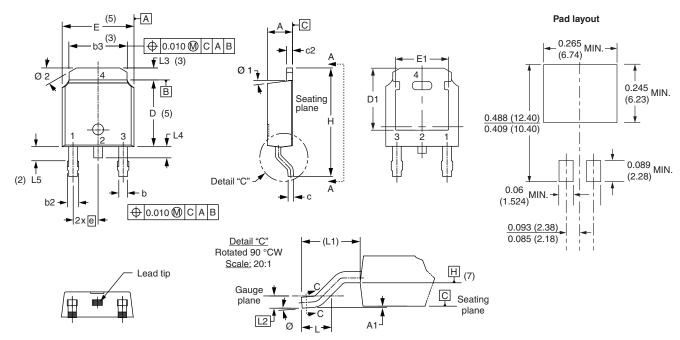
0.050

0.040

0.060

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



Ī	SYMBOL	MILLIM	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		
	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STINIBUL	MIN.	MAX.	MIN.	MAX	
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41	
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07	
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51	0.51 BSC		0.020 BSC	
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05	
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04	
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06	
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



Legal Disclaimer Notice

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Revision: 02-Oct-12 Document Number: 91000